Finite temperature calculations of the electronic and optical properties of solids and nanostructures: the role of electron-phonon coupling from an Ab-Initio perspective



Real life is at finite temperature (I)



Real life is at finite temperature (II)

PHYSICAL REVIEW B

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Temperature dependence of the dielectric function and interband critical points in silicon

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The complex dielectric function $\epsilon(\omega)$ of Si was measured ellipsometrically in the 1.7-5.7-eV photon-energy range at temperatures between 30 and 820 K. The observed structures are analyzed by fitting the second-derivative spectrum $d^2\epsilon/d\omega^2$ with analytic critical-point line shapes. Results for the temperature dependence of the parameters of these critical points, labeled E'_0 , E_1 , E_2 , and E'_1 , are presented. The data show good agreement with microscopic calculations for the energy shift and the broadening of interband transitions with temperature based on the electron-phonon interaction. The character of the E_1 transitions in semiconductors is analyzed. We find that for Si and light III-V or II-VI compounds an excitonic line shape represents best the experimental data, whereas for Ge, α -Sn, and heavy III-V or II-VI compounds a two-dimensional critical point yields the best representation.



"... unfortunately theorists do not even bother to compare their calculations with low-temperature measurements, using more easily accessible room temperature spectra."



At the absorption threshold the QP lifetime is EXACTLY infinite



Real life is at finite temperature (III)



Electron-phonon today



Ultrafast Carrier Relaxation in Si Studied by Time-Resolved Two-Photon Photoemssion Spectroscopy: Intravalley Scattering and Energy Relaxation of Hot Electrons

See Monday's talk!









Are purely electronic theories reliable ???

<u>THE</u> limitations...



In this talk I will not extensively discuss formal aspects (vertex, conserving props., ...) I will (try) not do extensive and heavy math (see references for that) I will not talk about superconductivity, Fröhlich or Holstein Hamiltonians I will use LDA or GGA, nothing more complicated (including SC-GW)







Outline (II)

Ab-Initio Polarons

- The Heine-Allen-Cardona Approach (static)
- The Hedin-Lundqvist approach (dynamical)
- The Diagrammatic approach (dynamical)
 - Density Functional Perturbation Theory

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Finite temperature excitons

- The Bethe-Salpeter equation in the polaronic basis
- A phonon induced kernel for the Bethe-Salpeter equation
- Finite temperature optical spectra of solids



Spectral functions and the QP-approximation

• Quasiparticles and spectral functions

Polarons as entangled electron-phonon states





 $\vec{k} + \vec{q}$



 \vec{k}





$$\begin{array}{c} \textbf{The Heine-Allen-Cardona Approach} (\textbf{J}) \\ \text{For a review see M. Cardona, Solid State Commun. 133, 3 (2005).} \\ \hline \\ \textbf{For a review see M. Cardona, Solid State Commun. 133, 3 (2005).} \\ \hline \\ \textbf{H} = T + V_{SCF} (\{\textbf{R}_{Is}\}) \\ \textbf{R}_{Is} = \textbf{R}_{Is} + \textbf{u}_{Is} \\ \hline \\ \textbf{R}_{Is} = \textbf{R}_{Is} + \textbf{u}_{Is} \\ \hline \\ \textbf{M}^{(1)} = \sum_{Is} \frac{\partial V_{SCF}}{\partial \textbf{R}_{Is}} \textbf{u}_{Is} \\ \delta H^{(1)} = \sum_{Is} \frac{\partial V_{SCF}}{\partial \textbf{R}_{Is}} \textbf{u}_{Is} \\ \delta H^{(2)} = \frac{1}{2} \sum_{IsJt} \frac{\partial^2 V_{SCF}}{\partial \textbf{R}_{Is} \partial \textbf{R}_{Jt}} \textbf{u}_{Is} \textbf{u}_{Jt} \\ \delta E_{nk} = \sum_{IsJ} \left[\frac{1}{2} \langle \frac{\partial^2 V_{SCF}}{\partial \textbf{R}_{Is} \partial \textbf{R}_{Jt}} \rangle + \sum_{Is} (E_{nk} - E_{mp})^{-1} \langle \frac{\partial V_{SCF}}{\partial \textbf{R}_{Is}} | mp \rangle \langle mp | \frac{\partial V_{SCF}}{\partial \textbf{R}_{Jt}} | \textbf{u}_{Is} \textbf{u}_{Jt} \\ \hline \\ \textbf{Fan} \\ \hline \\ \textbf{Now we can rewrite the displacement operators} \\ \sum_{Is} \textbf{u}_{Is} \langle n' \textbf{k} + \textbf{q} | \frac{\partial V_{SCF}}{\partial \textbf{R}_{Is}} | n \textbf{k} \rangle = \sum_{q\lambda} g_{n'nk}^{q\lambda} (b_{q\lambda}^{\dagger} + b_{q\lambda}) \\ \hline \\ \delta E_{nk} = \sum_{q\lambda m} \frac{\left| g_{n'nk}^{q\lambda} \right|^2}{E_{nk} - E_{mk} + \textbf{q}} (2N_{q\lambda} + 1) \\ \hline \end{array}$$

The Heine-Allen-Cardona Approach (II)



neglected

The Heine-Allen-Cardona Approach (III)









$$\frac{hedin-Lundqvist}{R_{VL, PRB} 69, 115110 (2004)} = \frac{\delta n(x,t)}{\delta \phi(x',t')} \sim P_e(x,t;x',t)$$

$$\frac{\delta N(x,t)}{\delta \phi(x',t')} \sim D(x,t;x',t)$$

$$W = \cdots = W_{ph}(\mathbf{r}_1,\mathbf{r}_2,w)$$

$$W = \cdots$$



 $\omega \approx \epsilon_{nk}$ $\left|\epsilon_{nk}-\epsilon_{n'k-q}\right|\gg\omega_{q\lambda}$



Fan term in Heine-Allen-Cardona Theory

Density Functional Perturbation Theory

[S. Baroni, REVIEWS OF MODERN PHYSICS, 2001, 73, 515]



DFPT is composed by a self-consistent linear system

By working out the DFPT definition of the KS potential it is possible to link DFPT to the static limit of the electron-phonon potential defined in MBPT





Excitons: the polaronic picture



The dynamical BSE



The dynamical BSE II: the phonon term





 $\tau^{\lambda}(T) = \left[2\Im\left(E_{\lambda}(T)\right)\right]^{-1}$

Finite T excitons

AM, Phys. Rev. Lett. 101, 106405 (2008)



Giant polaronic effects in nanostructures





Spectral Functions and QP picture $G_{n\mathbf{k}}(\omega) = \frac{1}{\omega - \epsilon_{n\mathbf{k}} - \sum_{n\mathbf{k}}(\omega) + i\eta}$ Real Particle SF $G_{n\mathbf{k}} = \langle n\mathbf{k} \mid (\omega - H)^{-1} \mid n\mathbf{k} \rangle$ $E_{I\mathbf{k}} = E_{c\mathbf{k}}^{(0)}$ ω $G_{n\mathbf{k}}(\omega) = \sum |\langle \Psi | c_{n\mathbf{k}}^{\dagger} (I\mathbf{k})|^{2} (\omega - E_{I\mathbf{k}})^{-1}$ Quasi Particle SF, $Z_{n\mathbf{k}}$ $E_{I\mathbf{k}} \to A_{n\mathbf{k}}(\omega) = \sum |\langle \Psi | c_{n\mathbf{k}}^{\dagger} | I\mathbf{k} \rangle|^{2} \delta(\omega - E_{I\mathbf{k}})$ $E_{I\mathbf{k}} = E_{n\mathbf{k}}^{QP} + i\Gamma_{n\mathbf{k}}^{QP}$ **Spectral Functions** Expanding in eigenstates of the total Hamiltonian the QP picture holds when there is a dominant (and sharp!) pole that collects most of electronic charge



PHYSICAL REVIEW

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1 AUGUST 1963

Coupled Electron-Phonon System*

S. ENGELSBERG Palmer Physical Laboratory, Princeton University, Princeton, New Jersey

AND

J. R. SCHRIEFFER University of Pennsylvania, Philadelphia, Pennsylvania (Received 26 March 1963)

$$\Sigma_{n\mathbf{k}}^{Fan}(\omega) = \sum_{\mathbf{q}\lambda} \frac{1}{N_{\mathbf{q}}} \sum_{n'} \mid g_{n'n\mathbf{k}}^{\mathbf{q},\lambda} \mid^2 \left[\frac{B(\omega_{\mathbf{q}\lambda}) + 1 - f_{n'\mathbf{k}-\mathbf{q}}}{\omega - \epsilon_{n'\mathbf{k}-\mathbf{q}} - \omega_{\mathbf{q}\lambda} - i0^+} + \frac{B(\omega_{\mathbf{q}\lambda}) + f_{n'\mathbf{k}-\mathbf{q}}}{\omega - \epsilon_{n'\mathbf{k}-\mathbf{q}} + \omega_{\mathbf{q}\lambda} - i0^+} \right]$$

Debye Model in the HEG At zero temperature



$$\Sigma^{Fan}(\omega) = i g^{2} \int d^{4}k (2\pi)^{-4} D(p-k) G(k)$$
$$D(p-k) = ((p_{0}-k_{0})^{2} - \omega^{2} + i\eta)^{-1} \qquad G(k) = (k_{0} - \epsilon_{k} \pm i\eta)^{-1}$$

Spectral Functions in the HEG (II)



Spectral Functions in the HEG (III)



Dynamical effects in Diamond !



C-based nanostructures: polymers





Zero-Point Motion $\langle u^2(T) \rangle \simeq \frac{\hbar}{4M\Omega} \langle 1 + 2\mathcal{N}_{bose}(T) \rangle$ $\langle u_C^2 \rangle \approx 0.2 a.u.$ $\sqrt{\langle u^2 \rangle} \approx 0.1 a.u.$ $\sqrt{\langle u^2 \rangle} \approx 0.4 a.u.$ $\langle u_{\mu}^2 \rangle \approx 0.3 a.u.$ <u>Science</u> **280** Integrated Optoelectronic Devices Based on Conjugated Polymers 1741 (1998)

Henning Sirringhaus, * Nir Tessler, Richard H. Friend

An all-polymer semiconductor integrated device is demonstrated with a high-mobility conjugated polymer field-effect transistor (FET) driving a polymer light-emitting diode (LED) of similar size. The FET uses regioregular poly(hexylthiophene). Its penormance approaches that of inorganic amorphous silicon FETs, with field-effect mobilities of 0.05 to 0.1 square centimeters per volt second and ON-OFF current ratios of >106. The high mobility is attributed to the formation of extended polaron states as a result of local self-organization, in contrast to the variable-range hopping of self-localized polarons found in more disordered polymers. The FET-LED device represents a step toward all-polymer optoelectronic integrated circuits such as active-matrix polymer LED displays.

Breakdown of the QP picture



E. Cannuccia, Phys. Rev.



Polarons in an Hamiltonian representation (II)



Are polymers an isolated case ?



Spectral Functions solids @ the CBM and VBM





Yambo: an ab-initio tool for excited state calculations



Yambo: an ab-initio tool for R&D





Optimal MPI (and, shortly, OpenMP) Paralellization

Improved and efficient memory distribution

Interfaced to common and well-known ground-state GPL codes: abinit, QEspresso, CPMD

Development work-in-progress within the PRACE (Partnership for Advanced Computing in Europe) in collaboration with the Italian and Portughese Super-Computing centers

> Yambo: an ab-initio tool for excited state calculations, Andrea Marini, Conor Hogan, Myrta Grüning, Daniele Varsano, Comp. Phys. Comm. **180**, 1392 (2009)

cronic Correlation		Real Particles	upling	Polaronic—induced effect can be <u>HUGE</u> . They can even lead to the <u>breakdown</u> of the		
		Quasi Particles	Phonon Co	 < 50 A 51 - 90 91 - 150 151 - 230 231 - 330 331 - 450 ≥ 450 	ture The w counterba energy (~1	
Elect	Cother Porting	Multi-component particles		Potential ground-breaking consequences on mobility, optical properties,transpo		
	Ya M http:	bo //www.yambo-code	e.org/		Critical pure	<u>re-exam</u> lu electi
Plane-Wave Self-Consistent Field "The computer is a tool for clear thinking" Freeman J. Dyson					structi base	ire calcu d nanos

http://www.pwscf.org

Conclusions

eak correlation is

alanced by the lowactivation process Debye energy)

3 rtooo



nination of ALL ronic bandlations on Ctructures ?

People and references...



Giant polaronic effects in polymers: breakdown of the guasiparticle picture

PhD Thesis (2011)

Elena Cannuccia

http://www.yambo-code.org/papers/Thesis_Elena_Cannuccia.pdf

E. Cannuccia and AM "Ab initio study of entangled electron-phonon states in polymers", submitted to Phys. Rev. B (2012)

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AM "Ab-Initio Finite Temperature Excitons", Phys. Rev. Lett. 101, 106405 (2008)



M. Cardona, Solid State Commun. 133, 3 (2005).

L. Hedin and S. Lundqvist, Solid. State Phys. 23, 1 (1969)

R. von Leeuwen, PRB **69**, 115110 (2004)